NSN 5961-01-294-1290

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-1290 **Inclosure Material:** Metal **Overall Length:** 0.011 inches **Terminal Length:** 0.010 inches **Overall Height:** 0.004 inches **Overall Width:** 0.007 inches **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 reverse voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 beam lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0